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Surface dimerization induced CuPt$_B$ versus CuPt$_A$ ordering of GaInP alloys

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Using a valence force field approach and ab initio pseudopotential calculations, we examine the role of subsurface strain in the ordering of Ga$_{0.53}$In$_{0.47}$P alloys. We show that depending on the orientation of the surface phosphorus dimers, these alloys can have (i) a CuPt$_A$ ordering for 1×2 or c(4×4) reconstruction; (ii) a CuPt$_B$ ordering for 2×1 or β(2×4) reconstruction; and (iii) a triple period ordering for 2×3 or c(8×6) reconstruction. These results are in good agreement with recent experiments of Gomyo et al. [Phys. Rev. Lett. 72, 673 (1994); Jpn. J. Appl. Phys. 34, L469 (1995)]. © 1995 American Institute of Physics.

Spontaneous ordering of III–V alloys has now been extensively observed and characterized in many semiconductors.1 The most frequently seen spontaneous ordering consists of monolayer superlattice alternation along the [111] cubic body diagonals.2 Of the four bulk-equivalent body diagonals, ordering has been seen to take place along only two directions ([111] and [111], called CuPt$_B$ variants), while, until recently, ordering along the other two directions ([111] and [111], called CuPt$_A$ variants) was absent. Theoretical studies2–4 have demonstrated the relationship between surface reconstruction and spontaneous ordering in the 2D surface plane. It was shown that a cation-terminated 2×2 surface reconstruction leads to a 2D CuPt$_B$ ordering in the top surface layer and in the fourth subsurface layer, while an anion-terminated 2×1 reconstruction leads to strong CuPt$_B$ ordering in the third subsurface layer. The occurrence of ordering in these layers, depending on reconstruction type, illustrates the intimate relation between top surface growth morphology and the depth of the ordering layer. It was further shown4 that the main thermodynamic driving force for ordering is the creation of a subsurface selectivity for occupation by a small atom (Ga) under the strained dimer rows, and occupation by a large atom (In) underneath the opening between dimer rows. This subsurface selectivity induced by the top surface dimers depends naturally on the dimer orientation. The latter changes with reconstruction pattern. The subsurface selectivity in a given layer further depends on the depth of this layer under the top surface. Thus, nonflat surfaces can have a corresponding range of depths of subsurface ordering.

Several significant experimental observations were recently made in this respect. First, Gomyo et al.5 discovered, under MBE growth conditions favoring an anion-rich 2×3 surface reconstruction, a triple period ordering of Al$_{0.48}$In$_{0.52}$As/InP(001), in either the [111] or the [111] directions. Philips et al.6 recently also observed, in (001) In$_{0.55}$Ga$_{0.47}$As MBE epi-layers, a triple period ordering in two directions: [111] and [111]. Second, Gomyo et al.7 discovered a CuPt$_A$ ordering of Al$_{0.33}$In$_{0.67}$P/GaAs(001) under MBE growth conditions favoring an anion-terminated 2×2 reconstruction (with 1×2 basic building blocks). In contrast, the conventional higher growth temperature $T\sim560$ °C produces the 2×1 reconstruction that leads to CuPt$_B$ ordering.1,5 Both the 2×2 and 2×3 surface reconstructions occur at low growth temperatures (520 °C for 2×2 and 415 and 460 °C for 2×3, respectively) and are hence believed to be more anion-rich than the 2×1 surface. Such reconstructions with heavy excess (>1 monolayer) of anions were not studied theoretically before since the nature of the surface structure under heavy anion coverage has become clear only recently.8

In this letter, we show via total energy minimization that (i) the anion-terminated 2×1 surface reconstruction stabilizes 2D CuPt$_B$ ordering of the Ga$_{0.53}$In$_{0.47}$P alloy by 88 meV/surface atom; (ii) the 1×2 double P layer reconstruction (a simplified version of the 2×2 reconstruction) stabilizes CuPt$_A$ ordering by 155 meV/surface atom while (iii) the 2×3 surface stabilizes a triple-period ordering by 97 meV/surface atom. These large stabilization energies are predicted to lead to a significant (~60%) degree of ordering at growth temperatures. Our results confirm the suggestion of Gomyo et al.5,7 via a thermodynamic theory.

We first concentrate on the main distinguishing features of various reconstructions5,7 [Fig. 1(a)]: observe that while both the 2×1 and the 1×2 surfaces are terminated by P dimers, due to the occurrence of double phosphorus layers in the 1×2 surface, its P–P dimers are rotated by 90° with respect to those of the 2×1 surface. The 2×3 surface, on the other hand, can be viewed as a combination of the 1×2 and 2×1 surfaces, the former occupying 2/3 of the total projected surface area. We conducted elastic energy minimization calculations via a valence-force-field (VFF) model (Refs. 2 and 4 and references therein) on various ordered patterns on the model 2×1, 1×2, and 2×3 surfaces, thus establishing the basic relation between dimer orientation and type of stable ordering. Conclusions draw from these calculations were then examined by more sophisticated first principles self-consistent calculations on realistic8–10 but complicated β2(2×4) and c(4×4) surfaces, containing, respectively, the building blocks (or motifs) of the 2×1 and 1×2 model surfaces.

The total VFF elastic energy is minimized with respect to atomic displacements subject to the constraint that surface P–P dimers are fixed at the dimer geometry determined by self-consistent pseudopotential calculations.10 The contribution of all surface layer P–P dimer bonds is omitted from the elastic energy. We use as input to the VFF calculations the equilibrium bond lengths and force constants determined from first-principles pseudopotential calculations3,4 for zinc-
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FIG. 1. (a) Top and side views of the 2×1, 1×2, and 2×3 model surface reconstructions. The filled and open circles indicate anion and cation sites, respectively, with sizes descending from top surfaces. The cation sites reconstructions. The filled and open circles indicate anion and cation sites, respectively, for the 2×1, 1×2, and 2×3 surfaces. Negative energies in Fig. 1(c) mean stable structures. A 2×2 superperiodicity is used in Fig. 2(a) for the 2×1 and 1×2 surfaces, but not for the 2×3 surface. A primitive 2×3 surface cell has ten different occupation patterns. Some of them are degenerate. Here, we show in Fig. 2(b) the five nondegenerate patterns: T1, T2, CuPt B , NT1, and NT2. Out of the five, only T1 and T2 may evolve into triple period ordering in the [110] direction. We observe from Fig. 1 the following. (i) The 2×1 surface exhibits a strong CuPt B ordering at the third subsurface layer (ordering energy ΔE ord =88 meV/surface atom). The ordering direction is [110], which is the dimerization direction of this surface. (ii) The 1×2 surface shows a strong CuPt A ordering at the second subsurface layer with ΔE ord =155 meV/surface atom. The ordering occurs along [110], which is the dimerization direction of this surface. (iii) While in the 2×1 surface, the relaxation of the first subsurface layer has but a small effect on the ordering energy at Y-third subsurface layer; a much larger first subsurface layer relaxation effect occurs in the 1×2 surface that orders at the Y-second subsurface layer. This reflects the importance of atomic relaxations at the immediate vicinity of the ordered layer Y in minimizing strain energies. Without first subsurface layer relaxation, the ordering energy in the 1×2 surface is 287 rather than 155 meV/surface atom. (iv) The 2×3 surface shows a strong three-period ordering with ΔE ord =97 meV/surface atom. The ordering direction is [110], which coincides with the dimerization direction of the top layer of this surface.

Results (i), (ii), and (iv) are in good accord with recently suggested qualitative correlations between surface reconstruction and alloy ordering by Gomyo et al. 5,7 Our calculations further establish a quantitative thermodynamic incentive for such correlations, which can be readily understood from surface geometries: anions are normally second nearest

placed at the Y-third, second, and second subsurface layer, respectively, for the 2×1, 1×2, and 2×3 surfaces. Negative energies in Fig. 1(c) mean stable structures. A 2×2 superperiodicity is used in Fig. 2(a) for the 2×1 and 1×2 surfaces, but not for the 2×3 surface. A primitive 2×3 surface cell has ten different occupation patterns. Some of them are degenerate. Here, we show in Fig. 2(b) the five nondegenerate patterns: T1, T2, CuPt B , NT1, and NT2. Out of the five, only T1 and T2 may evolve into triple period ordering in the [110] direction. We observe from Fig. 1 the following. (i) The 2×1 surface exhibits a strong CuPt B ordering at the third subsurface layer (ordering energy ΔE ord =88 meV/surface atom). The ordering direction is [110], which is the dimerization direction of this surface. (ii) The 1×2 surface shows a strong CuPt A ordering at the second subsurface layer with ΔE ord =155 meV/surface atom. The ordering occurs along [110], which is the dimerization direction of this surface. (iii) While in the 2×1 surface, the relaxation of the first subsurface layer has but a small effect on the ordering energy at Y-third subsurface layer; a much larger first subsurface layer relaxation effect occurs in the 1×2 surface that orders at the Y-second subsurface layer. This reflects the importance of atomic relaxations at the immediate vicinity of the ordered layer Y in minimizing strain energies. Without first subsurface layer relaxation, the ordering energy in the 1×2 surface is 287 rather than 155 meV/surface atom. (iv) The 2×3 surface shows a strong three-period ordering with ΔE ord =97 meV/surface atom. The ordering direction is [110], which coincides with the dimerization direction of the top layer of this surface.

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neighbor atoms in their normal tetrahedral positions, but at the surface they form dimers and are thus displaced towards each other by a sizeable amount (~0.8 Å each). This creates a compressive strain on the subsurface layer atoms lying directly below the dimer rows [the cation site \(\alpha\) in Fig. 1(a)], and a tensile strain on atoms underneath the opening between the dimer rows\(^4\) [i.e., the cation site \(\beta\) in Fig. 1(a)].

This undulating subsurface strain leads to a preference\(^4\) for a small atom (Ga) at the compressed site \(\beta\) and a large atom (In) at the expanded site \(\alpha\).

We will not pursue in this letter the question of layer stacking, i.e., 3D ordering as (a) this is not essential to explain CuPt\(_A\) vs. CuPt\(_B\) ordering and (b) it involves many additional factors including surface steps that select the sub-variants of CuPt\(_A\), or those of CuPt\(_B\). Recent pseudopotential calculation of surface formation energies versus phosphorus chemical potential\(^{10}\) suggested that only samples grown with heavy excessive surface P atoms would have the desired 1×2 or 2×3 structural pattern. This often requires temperature growth as achieved by Gomyo et al.\(^{15,7}\)

More elaborate first-principles total energy calculations on realistic surfaces support the conclusions derived here from elastic energy calculations on model systems. Using a pseudopotential method, we have calculated the total energies for Ga\(_{0.5}\)In\(_{0.5}\)P surfaces with realistic surface reconstructions—the \(\beta(2\times4)\) reconstruction for single P layer \(2\times1\) surface and the \(c(4\times4)\) reconstruction for the double P layer \(1\times2\) surface. (Realistic surfaces have larger unit cell sizes than model surfaces, since the former have surface charge compensation requiring many atoms.) To compare the results of the first-principles and VFF calculations, we have calculated the respective order parameter \(\eta\), which measures the degree of 2D ordering regardless of the details of surface reconstructions. In particular, we group all distinct cation sites in layer \(Y\) into two 2D sublattices \{\(\alpha\)\} and \{\(\beta\)\} along the ordering direction. Assuming \(c_\alpha\) and \(c_\beta\) are the indium concentrations of \{\(\alpha\)\} and \{\(\beta\)\}, respectively, the order parameter is simply \(\eta = c_\alpha - c_\beta\). If \(c_\alpha = 1\), then \(\eta = 1\), indicating perfect ordering. If, on the other hand, \(c_\alpha = 0.5\), one would have \(c_\beta = 0.5\), and thus \(\eta = 0\), indicating perfect randomness. The model \(2\times1\) and \(1\times2\) surfaces are special cases where all sites on sublattice \{\(\alpha\)\} are identical and all sites on sublattice \{\(\beta\)\} are identical as shown in Fig. 1(a).

Here, we evaluate \(\eta\) at second and third subsurface layers for \(c(4\times4)\) and \(\beta(2\times4)\) surfaces, respectively, and correspondingly for the model \(1\times2\) and \(2\times1\) surfaces. The calculation was done following Osorio et al.\(^4\) by assigning an on-site energy \(\Delta J_\alpha^{(\text{on})}\) and finding its occupation probability \(c_\alpha(T)\) using the Bragg–Williams method. Figure 3 shows that \(\eta\) derived from first-principles calculations with the \(\beta(2\times4)\) and \(c(4\times4)\) surface reconstructions follow the same trends (with smaller magnitude) as those derived from VFF calculations using the \(2\times1\) and \(1\times2\) surfaces. The smaller magnitude of \(\eta\) is expected as the more complicated reconstruction patterns of the realistic surfaces have defect-like surface features absent in the model surfaces that do not serve to promote ordering energies. Figure 3 shows that both the pseudopotential and the VFF calculation predict a stronger 2D ordering for the double P layer \([c(4\times4)\) and \(1\times2]\) surface than that of the single P layer \([\beta(2\times4)\) and \(2\times1]\) surface.

In summary, we showed via thermodynamic energy minimization that the orientation of surface phosphorus dimers correlates with the type of ordering—CuPt\(_A\), CuPt\(_B\), and a triple period ordering—in Ga\(_{0.5}\)In\(_{0.5}\)P in good agreement with experiments.

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